

L Number	Hits	Search Text	DB	Time stamp
1	4	(macro with embed\$4 with standard) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 17:43
2	0	(macro with pitch with standard) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 17:43
3	0	((macro with standard) same pitch) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 17:43
4	15	((macro with standard) same pitch)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:02
5	2	5539224.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:05
6	2	5342794.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:07
7	3	3461361.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:08
8	2	5286518.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:12
9	2	5410173.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:13
10	2	4742383.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:14
11	2	5313079.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 18:15
-	17993	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same drain same gate	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:15
-	13832	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:17
-	3587	((((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with gate)) same inverter	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:17
-	72	(((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with gate) same inverter) same polysilicon	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:17
-	659	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with gate with polysilicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:17
-	41	(((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with gate with polysilicon)) same inverter	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:17

	20	((((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with gate with polysilicon)) same inverter) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:33
	17	((n adj channel) or "n-channel") with ((p adj channel) or "p-channel") with drain with gate with "same" with silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:54
	9	((((n adj channel) or "n-channel") with ((p adj channel) or "p-channel") with drain with gate with "same" with silicon) and (@ad<19931227 or @rlad<19931227))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:39
	0	(trace with gate with coplanar) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 18:04
	10	trace with gate with coplanar	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:39
	27	((n adj channel) or "n-channel") with ((p adj channel) or "p-channel") same (drain with gate with "same" with silicon with form\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 18:02
	17	((((n adj channel) or "n-channel") with ((p adj channel) or "p-channel") same (drain with gate with "same" with silicon with form\$3)) and (@ad<19931227 or @rlad<19931227))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 17:55
	4	drain with gate with "same" with silicon with elevated	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 18:03
	130	drain with gate with silicon with elevated	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 18:13
	24	(drain with gate with silicon with elevated) and (@ad<19931227 or @rlad<19931227))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:17
	11	((drain with gate with silicon with elevated) and (@ad<19931227 or @rlad<19931227)) and ((n adj channel) or "n-channel") same ((p adj channel) or "p-channel")	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 18:05
	113	drain with gate with silicon with raised	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 18:14
	17	(drain with gate with silicon with raised) and (@ad<19931227 or @rlad<19931227))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/06 18:24
	1058	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") and (drain with "same" with gate with layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 13:02
	326	((((n adj channel) or "n-channel") same ((p adj channel) or "p-channel")) and (drain with "same" with gate with layer)) and (@ad<19931227 or @rlad<19931227))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:17
	198	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with "same" with gate with layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:17
	80	((((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with "same" with gate with layer)) and (@ad<19931227 or @rlad<19931227))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:52

	16994	etch\$3 with gate with substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:53
	0	(etch\$3 with gate with substrate) with from	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:51
	269	(etch\$3 with gate with substrate) same (drain with gate with "same" with layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:54
	57	((etch\$3 with gate with substrate) same (drain with gate with "same" with layer)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:54
	2888	form\$3 with gate with (substrate near2 etch\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 12:54
	25	(form\$3 with gate with (substrate near2 etch\$3)) same (drain with gate with "same" with layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 14:50
	5	((form\$3 with gate with (substrate near2 etch\$3)) same (drain with gate with "same" with layer)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 13:02
	217	inverter with trace	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 13:01
	4	((inverter with trace) and ((n adj channel) or "n-channel") same ((p adj channel) or "p-channel")) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 13:32
	25	(inverter with trace) and ((n adj channel) or "n-channel") same ((p adj channel) or "p-channel")	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 13:07
	125	trace with connect\$3 with drain	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 13:31
	26	(trace with connect\$3 with drain) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 14:51
	3	("4181860"   "4387433"   "4433384").PN.	USPAT	2004/04/07 14:44
	1694	connect\$3 with drain with "adjacent" with transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 14:49
	33	(connect\$3 with drain with "adjacent" with transistor) same (drain with gate with "same" with layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 14:51
	15	((connect\$3 with drain with "adjacent" with transistor) same (drain with gate with "same" with layer)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 15:08
	29	cmos with gate with drain with form\$3 with "same" with layer	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 15:13
	9	(cmos with gate with drain with form\$3 with "same" with layer) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 15:14

	18	inverter same (gate with drain with form\$3 with "same" with layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 15:14
-	8	(inverter same (gate with drain with form\$3 with "same" with layer)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 16:05
-	0	(macro same (first with layer with metallization) same (second with layer with metallization with interconnect with macro)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 16:06
-	2	(macro same ((first or second) with layer with metallization) same (interconnect with macro)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 16:08
-	4	(macro and ((first or second) with layer with metallization) and (interconnect with macro)) and (@ad<19931227 or @rlad<19931227)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/07 17:36